










	<h2 style="color: red;">FQP17N08L</h2>
	Hersteller-Teilenummer: FQP17N08L
	Hersteller / Marke: AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung: MOSFET N-CH 80V 16.5A TO-220
	Datenblätter: <ul style="list-style-type: none">  1.FQP17N08L.pdf  2.FQP17N08L.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 39365 pcs Stock Available.
	Liefern von: Hong Kong
	Versandweg: DHL/Fedex/TNT/UPS/EMS
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQP17N08L
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 80V 16.5A TO-220
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	39365 pcs Stock
detaillierte Beschreibung	N-Channel 80V 16.5A (Tc) 65W (Tc) Through Hole TO-
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220-3
Verlustleistung (max)	65W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	80V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	16.5A (Tc)
Rds On (Max) @ Id, Vgs	100 mOhm @ 8.25A, 10V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	11.5nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	520pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	5V, 10V
Vgs (Max)	±20V
Verpackung	Tube
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)



















































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Sie können auch interessiert sein:

 <p>FQP17N08 Fairchild/ON Semiconductor MOSFET N-CH 80V 16.5A TO-220</p>	 <p>FQP17P06 Fairchild/ON Semiconductor MOSFET P-CH 60V 17A TO-220</p>	 <p>FQP16N25C Fairchild/ON Semiconductor MOSFET N-CH 250V 15.6A TO-220</p>	 <p>FQP16N25C AMI Semiconductor / ON Semiconductor MOSFET N-CH 250V 15.6A TO-220</p>
 <p>FQP16N35 FA FQP16N35 FA</p>	 <p>FQP17P06 AMI Semiconductor / ON Semiconductor MOSFET P-CH 60V 17A TO-220</p>	 <p>FQP17N08L Fairchild/ON Semiconductor MOSFET N-CH 80V 16.5A TO-220</p>	 <p>FQP17N40 Fairchild/ON Semiconductor MOSFET N-CH 400V 16A TO-220</p>

heiße Teile

Mehr

 FQP13N60C	 FQP140N03	 FQP140N03L	 D FQP14N15	 FQP14N15
 FQP14N30	 FQP14N30	 D FQP14N80	 FQP14N80C	 FQP15N16
 FQP15N30	 FQP15N50	 FQP15N60	 FQP15N65	 FQP15N80
 D FQP15P12	 FQP15P12	 FQP16N15	 FQP16N15	 FQP16N25
 FQP16N25	 FQP16N25C	 FQP16N25C	 FQP17N08	 FQP17N08
 FQP17N08L	 FQP17N40	 D FQP17N40	 FQP17P06	 FQP17P06
 FQP17P10	 D FQP17P10	 FQP18N20V2	 FQP18N20V2	 FQP18N50V2
 FQP18N50V2	 FQP19N10	 FQP19N10	 FQP19N10L	 FQP19N10L
 FQP19N20	 FQP19N20	 FQP19N20C	 D FQP19N20C	 FQP19N20L
 FQP19N20L	 FQP1N60C	 FQP20N06	 FQP20N06	 FQP20N06L

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